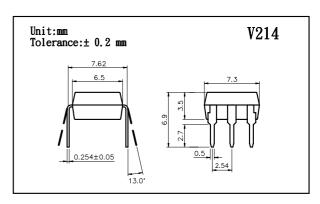
### V214/V214A

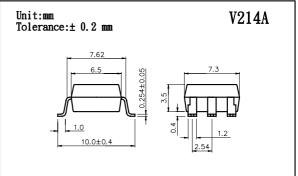
#### HIGH VOLTAGE, PHOTO BMOS RELAY

# COSMO

#### **FEATURES**

- Normally Open, Single Pole Single Throw
- Control 400VAC or DC Voltage
- Switch 130mA Loads
- LED control Current, 5mA
- Low ON-Resistance
- dv/dt, >500V/ms
- Isolation Test Voltage, 3750VACrms





### Absolute Maximum Ratings(Ta=25℃)

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Reverse Voltage	
Peak Forward Current	
Power Dissipation	
Derate Linearly from 25°C	, 3mW/°C
Detector(Output)	
Output Breakdown Voltage	. ± 400V

 Output Breakdown Voltage
 ± 400V

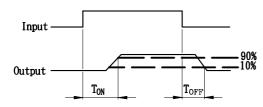
 Continuous Load Current
 ± 130mA

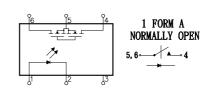
 Power Dissipation
 500mW

#### General Characteristics

deficial characteristics	
Isolation Test Voltage	. 3750VACrms
Isolation Resistance Vio=500V, Ta=25℃	≥10 <sup>10</sup> Ω
Total Power Dissipation	550mW
Derate Linearly from 25°C	2.5mW/℃
Storage Temperature Range40°C	to +125℃
Operating Temperature Range30°	°C to +85°C
Junction Temperature	100℃
Soldering Temperature, 2mm from case, 10 sec	260℃

● Turn on/Turn off time





# V214/V214A

### HIGH VOLTAGE, PHOTO BMOS RELAY

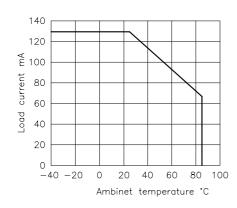
Characterisitcs (Ta=25°C)

(1a-25 C)								
Description			Symbol	Min.	Typ.	Max.	Unit	Test Condition
Emitter(Input)								
Forward Voltage			VF		1.2	1.5	V	IF=10mA
Operation Input Current			IFON			5	mA	VL=± 20V, IL=100mA
								t=10mS
Recovery Input Current			IFOFF	0.2			mA	VL=± 20V, IL<=5uA
Detector (output)								
Output Breakdown Voltage			VB	400			V	IB=50uA
Output Off-State Leakage			IT(0FF)		0.2	1	uA	VT=100V, IF=0mA
I/O Capacitance			CISO		6		рF	IF=0, f=1MHz
ON Resistance	Con- nection	A			20	30		
		В	RON		10	15	Ω	IL=100mA, IF=10mA
		С			5	7. 5		
Turn-on Time			TON		0.3	1.0	ms	IF=10mA, VL=± 20V
Turn-off Time			TOFF		0.7	1.5	ms	t=10ms, IL=± 100mA

Mos Relay Schematic and Wiring Diagrams						
Type	Schematic	Output configur -ation	Load	Con- nection	Wiring Diagrams	
			AC/DC	A	V <sub>N</sub> — Cood V <sub>L</sub> (AC,DC)	
V214 & V214A		1a	DC	В	VN	
					V <sub>M</sub> — F	
			DC	С	VN — FO T Load VL (DC)  2  3  4  CDC)	

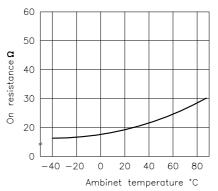
#### DATA CURVE

Allowable ambient temperature: -40°C to +85°C



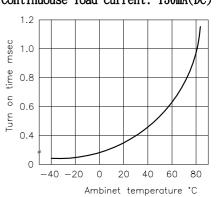
Load current vs. ambient temperature On resistance vs. ambient temperature Trun on time vs. ambient temperature Across terminals 4 and 6 pin LED current: 5mA

Continuouse load current: 130mA(DC)



Load voltage 400V(DC)

LED current: 5mA Continuouse load current: 130mA(DC)



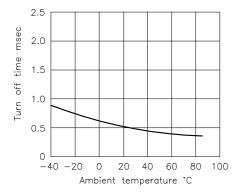
31

### V214/V214A

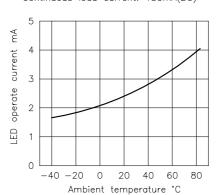
# HIGH VOLTAGE, PHOTO BMOS RELAY

#### V214/V214A

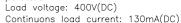
Turn off time vs. ambient temperature LED current: 5mA;Load voltage: 400V(DC) Continuous load current: 130mA(DC)

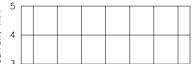


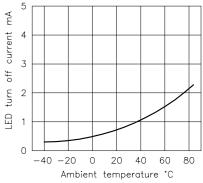
LED operate vs. ambient temperature Load voltage: 400V(DC) Continuous load current: 130mA(DC)



LED turn off current vs. ambient temperature

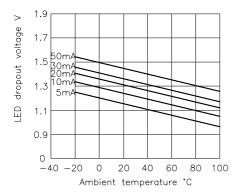






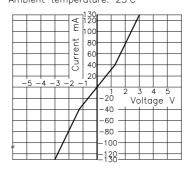
LED dropout voltage vs. ambient tempera-

LED current: 5 to 50mA

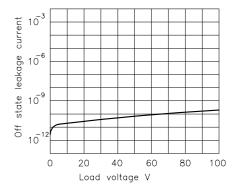


Voltage vs. current characteristics of output at MOS FET portion Measured portion: across terminals 4

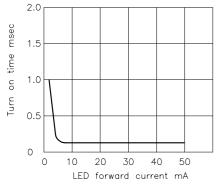
and 6 pin Ambient temperature: 25°C



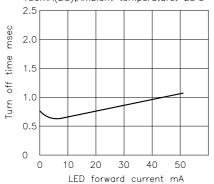
Off state leakage current Across terminals 4 and 6 pin Ambient temperature: 25°C



LED forward current vs. turn on time Across terminals 4 and 6 pin;Load voltage: 400V(DC);Continuous load current: 130mA(DC);Ambient temperature: 25°C



LED forward current vs. turn off time Across terminals 4 and 6 pin;Load vol tage: 400V(DC);Continuous load current: 130mA(DC);Ambient temperature: 25°C



Applied voltage vs. output capacitance Across terminals 4 and 6 pin Frequency: 1MHz;Ambient temperature: 25°C

